

Si5345/44/42 Rev D Data Sheet

10-Channel, Any-Frequency, Any-Output Jitter Attenuator/ Clock Multiplier

These jitter attenuating clock multipliers combine fourth-generation DSPLL[™] and MultiSynth[™] technologies to enable any-frequency clock generation and jitter attenuation for applications requiring the highest level of jitter performance. These devices are programmable via a serial interface with in-circuit programmable non-volatile memory (NVM) so they always power up with a known frequency configuration. They support free-run, synchronous, and holdover modes of operation, and offer both automatic and manual input clock switching. The loop filter is fully integrated on-chip, eliminating the risk of noise coupling associated with discrete solutions. Furthermore, the jitter attenuation bandwidth is digitally programmable, providing jitter performance optimization at the application level. Programming the Si5345/44/42 is easy with Silicon Labs' ClockBuilder Pro[™] software. Factory preprogrammed devices are also available.

Applications:

- OTN muxponders and transponders
- 10/40/100 G networking line cards
- GbE/10 GbE/100 GbE Synchronous Ethernet (ITU-T G.8262)
- Carrier Ethernet switches
- SONET/SDH line cards
- · Broadcast video
- · Test and measurement
- ITU-T G.8262 (SyncE) compliant

25-54 MHz XTAL

KEY FEATURES

- Generates any combination of output frequencies from any input frequency
- · Ultra-low jitter of 90 fs rms
- External Crystal: 25 to 54 MHz
- Input frequency range
 - Differential: 8 kHz to 750 MHz
 - LVCMOS: 8 kHz to 250 MHz
- Output frequency range
 - Differential: 100 Hz to 1028 MHz
 - LVCMOS: 100 Hz to 250 MHz
- Meets G.8262 EEC Option 1, 2 (SyncE)
- Highly configurable outputs compatible with LVDS, LVPECL, LVCMOS, CML, and HCSL with programmable signal amplitude
- Si5345: 4 input, 10 output, 64-QFN 9×9 mm
- Si5344: 4 input, 4 output, 44-QFN 7×7 mm
- Si5342: 4 input, 2 output, 44-QFN 7×7 mm



1. Features List

The Si5345/44/42 Rev D features are listed below:

- Generates any combination of output frequencies from any input frequency
- Ultra-low jitter of 90 fs rms
- Input frequency range
 - Differential: 8 kHz–750 MHz
 - LVCMOS: 8 kHz-250 MHz
- Output frequency range
 - Differential: 100 Hz to 1028 MHz
 - LVCMOS: 100 Hz to 250 MHz
- Programmable jitter attenuation bandwidth: 0.1 Hz to 4 kHz
- Meets G.8262 EEC Option 1, 2 (SyncE)
- Highly configurable outputs compatible with LVDS, LVPECL, LVCMOS, CML, and HCSL with programmable signal amplitude
- Status monitoring (LOS, OOF, LOL)
- · Hitless input clock switching: automatic or manual
- · Locks to gapped clock inputs
- Free-run and holdover modes

- Optional zero delay mode
- · Fastlock feature for low nominal bandwidths
- Glitchless on the fly output frequency changes
- DCO mode: as low as 0.001 ppb step size
- Core voltage
 - V_{DD}: 1.8 V ±5%
 - V_{DDA}: 3.3 V ±5%
- Independent output clock supply pins
 - 3.3 V, 2.5 V, or 1.8 V
- Serial interface: I²C or SPI
- In-circuit programmable with non-volatile OTP memory
- ClockBuilder Pro software simplifies device configuration
- Si5345: 4 input, 10 output, 64-QFN 9×9 mm
- Si5344: 4 input, 4 output, 44-QFN 7×7 mm
- Si5342: 4 input, 2 output, 44-QFN 7×7 mm
- Temperature range: -40 to +85 °C
- Pb-free, RoHS-6 compliant

2. Ordering Guide

Ordering Part Number (OPN)			Package	Temperature Range		
Si5345						
Si5345A-D-GM ^{1, 2}		0.001 to 1028 MHz	Integer and			
Si5345B-D-GM ^{1, 2}		0.001 to 350 MHz	Fractional	64-QFN	40 to 05 %	
Si5345C-D-GM ^{1, 2}	- 4/10	0.001 to 1028 MHz	late as a Oak	9×9 mm	–40 to 85 °C	
Si5345D-D-GM ^{1, 2}	-	0.001 to 350 MHz	Integer Only			
Si5344	1	1			I	
Si5344A-D-GM ^{1, 2}		0.001 to 1028 MHz	Integer and			
Si5344B-D-GM ^{1, 2}		0.001 to 350 MHz	Fractional	44-QFN		
Si5344C-D-GM ^{1, 2}	- 4/4	0.001 to 1028 MHz	late as a Oak	7×7 mm	–40 to 85 °C	
Si5344D-D-GM ^{1, 2}	-	0.001 to 350 MHz	Integer Only			
Si5342	1	1	I		I	
Si5342A-D-GM ^{1, 2}		0.001 to 1028 MHz	Integer and			
Si5342B-D-GM ^{1, 2}		0.001 to 350 MHz	Fractional	44-QFN		
Si5342C-D-GM ^{1, 2}	- 4/2	0.001 to 1028 MHz		7×7 mm	–40 to 85 °C	
Si5342D-D-GM ^{1, 2}	-	0.001 to 350 MHz	Integer Only			
Si5345/44/42-D-EVB	1				I	
Si5345-D-EVB						
Si5344-D-EVB	1 —		_	Evaluation Board	_	
Si5342-D-EVB						

2. Custom, factory preprogrammed devices are available. Ordering part numbers are assigned by Silicon Labs and the ClockBuilder Pro software. Custom part number format is "Si5345A-Dxxxxx-GM" where "xxxxx" is a unique numerical sequence representing the preprogrammed configuration.



*See Ordering Guide table for current product revision

** 5 digits; assigned by ClockBuilder Pro



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3. Functional Description

The Si5345's internal DSPLL provides jitter attenuation and any-frequency multiplication of the selected input frequency. Fractional input dividers (P) allow the DSPLL to perform hitless switching between input clocks (INx) that are fractionally related. Input switching is controlled manually or automatically using an internal state machine. The oscillator circuit (OSC) provides a frequency reference which determines output frequency stability and accuracy while the device is in free-run or holdover mode. The high-performance MultiSynth dividers (N) generate integer or fractionally related output frequencies for the output stage. A crosspoint switch connects any of the MultiSynth generated frequencies to any of the outputs. Additional integer division (R) determines the final output frequency.

3.1 Frequency Configuration

The frequency configuration of the DSPLL is programmable through the serial interface and can also be stored in non-volatile memory. The combination of fractional input dividers (P_n/P_d), fractional frequency multiplication (M_n/M_d), fractional output MultiSynth division (N_n/N_d), and integer output division (R_n) allows the generation of virtually any output frequency on any of the outputs. All divider values for a specific frequency plan are easily determined using the ClockBuilder Pro software.

3.2 DSPLL Loop Bandwidth

The DSPLL loop bandwidth determines the amount of input clock jitter attenuation. Register configurable DSPLL loop bandwidth settings in the range of 0.1 Hz to 4 kHz are available for selection. Since the loop bandwidth is controlled digitally, the DSPLL will always remain stable with less than 0.1 dB of peaking regardless of the loop bandwidth selection.

3.3 Fastlock Feature

Selecting a low DSPLL loop bandwidth (e.g. 0.1 Hz) will generally lengthen the lock acquisition time. The fastlock feature allows setting a temporary Fastlock Loop Bandwidth that is used during the lock acquisition process. Higher fastlock loop bandwidth settings will enable the DSPLLs to lock faster. Fastlock Loop Bandwidth settings of in the range of 100 Hz to 4 kHz are available for selection. The DSPLL will revert to its normal loop bandwidth once lock acquisition has completed.

3.4 Modes of Operation

Once initialization is complete the DSPLL operates in one of four modes: Free-run Mode, Lock Acquisition Mode, Locked Mode, or Holdover Mode. A state diagram showing the modes of operation is shown in Figure 3.1 Modes of Operation on page 8. The following sections describe each of these modes in greater detail.

3.4.1 Initialization and Reset

Once power is applied, the device begins an initialization period where it downloads default register values and configuration data from NVM and performs other initialization tasks. Communicating with the device through the serial interface is possible once this initialization period is complete. No clocks will be generated until the initialization is complete. There are two types of resets available. A hard reset is functionally similar to a device power-up. All registers will be restored to the values stored in NVM, and all circuits including the serial interface will be restored to their initial state. A hard reset is initiated using the RSTb pin or by asserting the hard reset register bit. A soft reset bypasses the NVM download. It is simply used to initiate register configuration changes.



Figure 3.1. Modes of Operation

3.4.2 Freerun Mode

The DSPLL will automatically enter freerun mode once power is applied to the device and initialization is complete. The frequency accuracy of the generated output clocks in freerun mode is entirely dependent on the frequency accuracy of the external crystal or reference clock on the XA/XB pins. For example, if the crystal frequency is ±100 ppm, then all the output clocks will be generated at their configured frequency ±100 ppm in freerun mode. Any drift of the crystal frequency will be tracked at the output clock frequencies. A TCXO or OCXO is recommended for applications that need better frequency accuracy and stability while in freerun or holdover modes.

3.4.3 Lock Acquisition Mode

The device monitors all inputs for a valid clock. If at least one valid clock is available for synchronization, the DSPLL will automatically start the lock acquisition process. If the fast lock feature is enabled, the DSPLL will acquire lock using the Fastlock Loop Bandwidth setting and then transition to the DSPLL Loop Bandwidth setting when lock acquisition is complete. During lock acquisition the outputs will generate a clock that follows the VCO frequency change as it pulls in to the input clock frequency.

3.4.4 Locked Mode

Once locked, the DSPLL will generate output clocks that are both frequency and phase locked to their selected input clocks. At this point, any XTAL frequency drift will not affect the output frequency. A loss of lock pin (LOL) and status bit indicate when lock is achieved. See 3.8.4 LOL Detection for more details on the operation of the loss-of-lock circuit.

3.4.5 Holdover Mode

The DSPLL will automatically enter holdover mode when the selected input clock becomes invalid and no other valid input clocks are available for selection. The DSPLL uses an averaged input clock frequency as its final holdover frequency to minimize the disturbance of the output clock phase and frequency when an input clock suddenly fails. The holdover circuit for the DSPLL stores up to 120 seconds of historical frequency data while locked to a valid clock input. The final averaged holdover frequency value is calculated from a programmable window within the stored historical frequency data. Both the window size and the delay are programmable as shown in the figure below. The window size determines the amount of holdover frequency averaging. The delay value allows ignoring frequency data that may be corrupt just before the input clock failure.



Figure 3.2. Programmable Holdover Window

When entering holdover, the DSPLL will pull its output clock frequency to the calculated averaged holdover frequency. While in holdover, the output frequency drift is entirely dependent on the external crystal or external reference clock connected to the XA/XB pins. If the clock input becomes valid, the DSPLL will automatically exit the holdover mode and re-acquire lock to the new input clock. This process involves pulling the output clock frequency to achieve frequency and phase lock with the input clock. This pull-in process is glitchless and its rate is controlled by the DSPLL or the Fastlock bandwidth.

The DSPLL output frequency when exiting holdover can be ramped (recommend). Just before the exit is initiated, the difference between the current holdover frequency and the new desired frequency is measured. Using the calculated difference and a user-selectable ramp rate, the output is linearly ramped to the new frequency. The ramp rate can be 0.2 ppm/s, 40,000 ppm/s, or any of about 40 values in between. The DSPLL loop BW does not limit or affect ramp rate selections (and vice versa). CBPro defaults to ramped exit from holdover. The same ramp rate settings are used for both exit from holdover and ramped input switching. For more information on ramped input switching, see 3.7.4 Ramped Input Switching.

Note: If ramped holdover exit is not selected, the holdover exit is governed either by (1) the DSPLL loop BW or (2) a user-selectable holdover exit BW.

3.5 External Reference (XA/XB)

An external crystal (XTAL) is used in combination with the internal oscillator (OSC) to produce an ultra low jitter reference clock for the DSPLL and for providing a stable reference for the free-run and holdover modes. A simplified diagram is shown in Figure 3.3 Crystal Resonator and External Reference Clock Connection Options on page 10. The device includes internal XTAL loading capacitors which eliminates the need for external capacitors and also has the benefit of reduced noise coupling from external sources. Refer to Table 5.12 Crystal Specifications on page 37 for crystal specifications. A crystal in the range of 48 MHz to 54 MHz is recommended for best jitter performance. The Si5345/44/42 Rev D Family Reference Manual provides additional information on PCB layout recommendations for the crystal to ensure optimum jitter performance.

To achieve optimal jitter performance and minimize BOM cost, a crystal is recommended on the XA/XB reference input. For SyncE pizza box applications (e.g. loop bandwidth set to 0.1 Hz), a TCXO is required on the XA/XB reference to minimize wander and to provide a stable holdover reference. See the Si5345/44/42 Rev D Family Reference Manual for more information. Selection between the external XTAL or REFCLK is controlled by register configuration. The internal crystal loading capacitors (CL) are disabled in the REFCLK mode. Refer to Table 5.3 Input Clock Specifications on page 26 for REFCLK requirements when using this mode. A PREF divider is available to accommodate external clock frequencies higher than 54 MHz. Frequencies in the range of 48 MHz to 54 MHz will achieve the best output jitter performance.

3.6 Digitally Controlled Oscillator (DCO) Mode

The output MultiSynths support a DCO mode where their output frequencies are adjustable in predefined steps defined by frequency step words (FSW). The frequency adjustments are controlled through the serial interface or by pin control using frequency increment (FINC) or decrement (FDEC). A FINC will add the frequency step word to the DSPLL output frequency, while a FDEC will decrement it. Any number of MultiSynths can be updated at once or independently controlled. The DCO mode is available when the DSPLL is operating in either free-run or locked mode.





Note: See Table 5.3 Input Clock Specifications on page 26.

3.7 Inputs (IN0, IN1, IN2, IN3)

There are four inputs that can be used to synchronize the DSPLL. The inputs accept both differential and single-ended clocks. Input selection can be manual (pin or register controlled) or automatic with user definable priorities.

3.7.1 Manual Input Switching (IN0, IN1, IN2, IN3)

Input clock selection can be made manually using the IN_SEL[1:0] pins or through a register. A register bit determines input selection as pin selectable or register selectable. The IN_SEL pins are selected by default. If there is no clock signal on the selected input, the device will automatically enter free-run or holdover mode. When the zero delay mode is enabled, IN3 becomes the feedback input (FB_IN) and is not available for selection as a clock input.

IN_SE	EL[1:0]	Selected Input		
			Zero Delay Mode Enabled	
0	0	INO	INO	
0	1	IN1	IN1	
1	0	IN2	IN2	
1	1	IN3	Reserved	

Table 3.1. Manual Input Selection Using IN_SEL[1:0] Pins

3.7.2 Automatic Input Selection (IN0, IN1, IN2, IN3)

An automatic input selection state machine is available in addition to the manual switching option. In automatic mode, the selection criteria is based on input clock qualification, input priority, and the revertive option. Only input clocks that are valid can be selected by the automatic clock selection state machine. If there are no valid input clocks available the DSPLL will enter the holdover mode. With revertive switching enabled, the highest priority input with a valid input clock is always selected. If an input with a higher priority becomes valid then an automatic switchover to that input will be initiated. With non-revertive switching, the active input will always remain selected while it is valid. If it becomes invalid an automatic switchover to a valid input with the highest priority will be initiated.

3.7.3 Hitless Input Switching

Hitless switching is a feature that prevents a phase offset from propagating to the output when switching between two clock inputs that have a fixed phase relationship. A hitless switch can only occur when the two input frequencies are frequency locked meaning that they have to be exactly at the same frequency, or at a fractional frequency relationship to each other. When hitless switching is enabled, the DSPLL simply absorbs the phase difference between the two input clocks during a input switch. When disabled, the phase difference between the two input clocks during a mean switch. The hitless switching feature supports clock frequencies down to the minimum input frequency of 8 kHz.

3.7.4 Ramped Input Switching

When switching between two plesiochronous input clocks (i.e., the frequencies are "almost the same" but not quite), ramped input switching should be enabled to ensure a smooth transition between the two inputs. Ramped input switching avoids frequency transients and overshoot when switching between frequencies and so is the default switching mode in CBPro. The feature should be turned off when switching between input clocks that are always frequency locked (i.e., are always the same exact frequency). The same ramp rate settings are used for both holdover exit and clock switching. For more information on ramped exit from holdover see 3.4.5 Holdover Mode.

3.7.5 Glitchless Input Switching

The DSPLL has the ability of switching between two input clock frequencies that are up to ±500 ppm apart. The DSPLL will pull-in to the new frequency using the DSPLL Loop Bandwidth or using the Fastlock Loop Bandwidth if enabled. The loss of lock (LOL) indicator will assert while the DSPLL is pulling-in to the new clock frequency. There will be no abrupt phase change at the output during the transition.

3.7.6 Input Configuration and Terminations

Each of the inputs can be configured as differential or single-ended LVCMOS. The recommended input termination schemes are shown in Figure 14. Differential signals must be ac-coupled, while single-ended LVCMOS signals can be ac- or dc-coupled. Unused inputs can be disabled and left unconnected when not in use.

Standard AC-Coupled Differential (IN0-IN3)



Standard AC-Coupled Single-Ended (IN0-IN3)



When 3.3V LVCMOS driver is present, C1 (optional), R1 and R2 may be needed to keep the signal at INx < 3.6 Vpp_se. See the Reference Manual for details.





See the Reference Manual for details on R1 and R2 values.

Figure 3.4. Termination of Differential and LVCMOS Input Signals

Note: See Table 5.3 Input Clock Specifications on page 26 and the Si5345/44/42 Rev D Family Reference Manual for more information.

3.7.7 Synchronizing to Gapped Input Clocks

The DSPLL supports locking to an input clock that has missing periods. This is also referred to as a gapped clock. The purpose of gapped clocking is to modulate the frequency of a periodic clock by selectively removing some of its cycles. Gapping a clock severely increases its jitter so a phase-locked loop with high jitter tolerance and low loop bandwidth is required to produce a low-jitter periodic clock. The resulting output will be a periodic non-gapped clock with an average frequency of the input with its missing cycles. For example, an input clock of 100 MHz with one cycle removed every 10 cycles will result in a 90 MHz periodic non-gapped output clock. This is shown in the following figure. For more information on gapped clocks, see "AN561: Introduction to Gapped Clocks and PLLs".



Figure 3.5. Generating an Averaged Clock Output Frequency from a Gapped Clock Input

A valid gapped clock input must have a minimum frequency of 10 MHz with a maximum of two missing cycles out of every eight. Locking to a gapped clock will not trigger the LOS, OOF, and LOL fault monitors. Clock switching between gapped clocks may violate the hitless switching specification in Table 5.8 Performance Characteristics on page 32 when the switch occurs during a gap in either input clock.

3.8 Fault Monitoring

All four input clocks (IN0, IN1, IN2, IN3/FB_IN) are monitored for loss of signal (LOS) and out-of-frequency (OOF) as shown in the figure below. The reference at the XA/XB pins is also monitored for LOS since it provides a critical reference clock for the DSPLL. There is also a Loss Of Lock (LOL) indicator which is asserted when the DSPLL loses synchronization.



Figure 3.6. Si5345/44/42 Fault Monitors

3.8.1 Input LOS Detection

The loss of signal monitor measures the period of each input clock cycle to detect phase irregularities or missing clock edges. Each of the input LOS circuits has its own programmable sensitivity which allows ignoring missing edges or intermittent errors. Loss of signal sensitivity is configurable using the ClockBuilder Pro software.

The LOS status for each of the monitors is accessible by reading a status register. The live LOS register always displays the current LOS state and a sticky register always stays asserted until cleared. An option to disable any of the LOS monitors is also available.



Figure 3.7. LOS Status Indicators

3.8.2 XA/XB LOS Detection

A LOS monitor is available to ensure that the external crystal or reference clock is valid. By default the output clocks are disabled when XAXB_LOS is detected. This feature can be disabled such that the device will continue to produce output clocks when XAXB_LOS is detected.

3.8.3 OOF Detection

Each input clock is monitored for frequency accuracy with respect to a OOF reference which it considers as its "0_ppm" reference. This OOF reference can be selected as either:

- XA/XB pins
- Any input clock (IN0, IN1, IN2, IN3)

The final OOF status is determined by the combination of both a precise OOF monitor and a fast OOF monitor as shown in the figure below. An option to disable either monitor is also available. The live OOF register always displays the current OOF state, and its sticky register bit stays asserted until cleared.



Figure 3.8. OOF Status Indicator

3.8.3.1 Precision OOF Monitor

The precision OOF monitor circuit measures the frequency of all input clocks to within $\pm 1/16$ ppm accuracy with respect to the selected OOF frequency reference. A valid input clock frequency is one that remains within the OOF frequency range which is register configurable up to ± 500 ppm in steps of 1/16 ppm. A configurable amount of hysteresis is also available to prevent the OOF status from toggling at the failure boundary. An example is shown in the figure below. In this case, the OOF monitor is configured with a valid frequency range of ± 6 ppm and with 2 ppm of hysteresis. An option to use one of the input pins (IN0–IN3) as the 0 ppm OOF reference instead of the XA/XB pins is available. This option is register configurable.



Figure 3.9. Example of Precise OOF Monitor Assertion and Deassertion Triggers

3.8.3.2 Fast OOF Monitor

Because the precision OOF monitor needs to provide 1/16 ppm of frequency measurement accuracy, it must measure the monitored input clock frequencies over a relatively long period of time. This may be too slow to detect an input clock that is quickly ramping in frequency. An additional level of OOF monitoring called the Fast OOF monitor runs in parallel with the precision OOF monitors to quickly detect a ramping input frequency. The Fast OOF monitor asserts OOF on an input clock frequency that has changed by greater than ±4000 ppm.

3.8.4 LOL Detection

The Loss Of Lock (LOL) monitor asserts a LOL register bit when the DSPLL has lost synchronization with its selected input clock.

There is also a dedicated loss of lock pin that reflects the loss of lock condition. The LOL monitor functions by measuring the frequency difference between the input and feedback clocks at the phase detector. There are two LOL frequency monitors, one that sets the LOL indicator (LOL Set) and another that clears the indicator (LOL Clear). An optional timer is available to delay clearing of the LOL indicator to allow additional time for the DSPLL to completely lock to the input clock. The timer is also useful to prevent the LOL indicator from toggling or chattering as the DSPLL completes lock acquisition. A block diagram of the LOL monitor is shown in the figure below. The live LOL register always displays the current LOL state and a sticky register always stays asserted until cleared. The LOL pin reflects the current state of the LOL monitor.



Figure 3.10. LOL Status Indicators

The LOL frequency monitors have an adjustable sensitivity which is register configurable from 0.1 ppm to 10,000 ppm. Having two separate frequency monitors allows for hysteresis to help prevent chattering of LOL status.

An example configuration where LOCK is indicated when there is less than 0.1 ppm frequency difference at the inputs of the phase detector and LOL is indicated when there's more than 1 ppm frequency difference is shown in the following figure.



Phase Detector Frequency Difference (ppm)

Figure 3.11. LOL Set and Clear Thresholds

Note: In this document, the terms, LVDS and LVPECL, refer to driver formats that are compatible with these signaling standards.

An optional timer is available to delay clearing of the LOL indicator to allow additional time for the DSPLL to completely lock to the input clock. The timer is also useful to prevent the LOL indicator from toggling or chattering as the DSPLL completes lock acquisition. The configurable delay value depends on frequency configuration and loop bandwidth of the DSPLL and is automatically calculated using the ClockBuilder Pro software.

3.8.5 Interrupt Pin (INTRb)

An interrupt pin (INTRb) indicates a change in state of the status indicators (LOS, OOF, LOL, HOLD). Any of the status indicators are maskable to prevent assertion of the interrupt pin. The state of the INTRb pin is reset by clearing the status register that caused the interrupt.

3.9 Outputs

Each driver has a configurable voltage swing and common mode voltage covering a wide variety of differential signal formats. In addition to supporting differential signals, any of the outputs can be configured as single-ended LVCMOS (3.3 V, 2.5 V, or 1.8 V) providing up to 20 single-ended outputs, or any combination of differential and single-ended outputs.

3.9.1 Output Crosspoint

A crosspoint allows any of the output drivers to connect with any of the MultiSynths as shown in the figure below. The crosspoint configuration is programmable and can be stored in NVM so that the desired output configuration is ready at power up.



Figure 3.12. MultiSynth to Output Driver Crosspoint

3.9.2 Output Signal Format

The differential output swing and common mode voltage are both fully programmable covering a wide variety of signal formats including LVDS and LVPECL. In addition to supporting differential signals, any of the outputs can be configured as LVCMOS (3.3 V, 2.5 V, or 1.8 V) drivers providing up to 20 single-ended outputs, or any combination of differential and single-ended outputs.

3.9.3 Differential Output Terminations

The differential output drivers support both ac-coupled and dc-coupled terminations as shown in the figure below.

Note: In this document, the terms, LVDS and LVPECL, refer to driver formats that are compatible with these signaling standards.





Figure 3.13. Supported Differential Output Terminations

Note: See the Si5345/44/42 Rev D Family Reference Manual for resistor values.

3.9.4 LVCMOS Output Terminations

LVCMOS outputs are dc-coupled, as shown in the following figure.

DC Coupled LVCMOS



Figure 3.14. LVCMOS Output Terminations

3.9.5 Programmable Common Mode Voltage For Differential Outputs

The common mode voltage (V_{CM}) for the differential modes are programmable so that LVDS specifications can be met and for the best signal integrity with different supply voltages. When dc coupling the output driver, it is essential that the receiver have a relatively high common mode impedance so that the common mode current from the output driver is very small.

3.9.6 LVCMOS Output Impedance Selection

Each LVCMOS driver has a configurable output impedance to accommodate different trace impedances. A source termination resistor is recommended to help match the selected output impedance to the trace impedance, where Rs = Transmission line impedance – Z_O . There are three programmable output impedance selections (CMOS1, CMOS2, CMOS3) for each VDDO option as shown in the following table.

VDDO		CMOS Drive Selections								
	OUTx_CMOS_DRV = 1	OUTx_CMOS_DRV = 2	OUTx_CMOS_DRV = 3							
3.3 V	38 Ω	30 Ω	22 Ω							
2.5 V	43 Ω	35 Ω	24 Ω							
1.8 V	-	46 Ω	31 Ω							

Table 3.2. Typical Output Impedance (Z_S)

3.9.7 LVCMOS Output Signal Swing

The signal swing (V_{OL}/V_{OH}) of the LVCMOS output drivers is set by the voltage on the VDDO pins. Each output driver has its own VDDO pin allowing a unique output voltage swing for each of the LVCMOS drivers.

3.9.8 LVCMOS Output Polarity

When a driver is configured as an LVCMOS output, it generates a clock signal on both pins (OUTx and OUTxb). By default, the clock on the OUTx pin is generated with the same polarity (in phase) as the clock on the OUTxb pin. The polarity of these clocks is configurable, enabling complementary clock generation and/or inverted polarity with respect to other output drivers.

3.9.9 Output Enable/Disable

The OEb pin provides a convenient method of disabling or enabling the output drivers. When the OEb pin is held high, all outputs are disabled. When held low, the outputs are enabled. Outputs in the enabled state can be individually disabled through register control.

3.9.10 Output Driver State When Disabled

The disabled state of an output driver is configurable as disable low or disable high.

3.9.11 Synchronous Output Disable Feature

The output drivers provide a selectable synchronous disable feature. Output drivers with this feature turned on will wait until a clock period has completed before the driver is disabled. This prevents unwanted runt pulses from occurring when disabling an output. When this feature is turned off, the output clock will disable immediately without waiting for the period to complete.

3.9.12 Zero Delay Mode

A zero delay mode is available for applications that require fixed and consistent minimum delay between the selected input and outputs. The zero delay mode is configured by opening the internal feedback loop through software configuration and closing the loop externally as shown in the figure below.

This helps to cancel out the internal delay introduced by the dividers, the crosspoint, the input, and the output drivers. Any one of the outputs can be fed back to the FB_IN pins, although using the output driver that achieves the shortest trace length will help to minimize the input-to-output delay. The OUT9 and FB_IN pins are recommended for the external feedback connection. The FB_IN input pins must be terminated and ac-coupled when zero delay mode is used. A differential external feedback path connection is necessary for best performance. Note that the hitless switching feature is not available when zero delay mode is enabled.



Figure 3.15. Si5345 Zero Delay Mode Setup

3.9.13 Output Divider (R) Synchronization

All the output R dividers are reset to a known state during the power-up initialization period. This ensures consistent and repeatable phase alignment across all output drivers. Resetting the device using the RSTb pin or asserting the hard reset bit will have the same result.

3.10 Power Management

Unused inputs and output drivers can be powered down when unused. Consult the Si5345/44/42 Rev D Family Reference Manual and ClockBuilder Pro software for details.

3.11 In-Circuit Programming

The Si5345/44/42 is fully configurable using the serial interface (l^2C or SPI). At power-up the device downloads its default register values from internal non-volatile memory (NVM). Application specific default configurations can be written into NVM allowing the device to generate specific clock frequencies at power-up. Writing default values to NVM is in-circuit programmable with normal operating power supply voltages applied to its V_{DD} and V_{DDA} pins. The NVM is two time writable. Once a new configuration has been written to NVM, the old configuration is no longer accessible. Refer to the Si5345/44/42 Rev D Family Reference Manual for a detailed procedure for writing registers to NVM.

3.12 Serial Interface

Configuration and operation of the Si5345/44/42 is controlled by reading and writing registers using the I^2C or SPI interface. The I2C_SEL pin selects I^2C or SPI operation. Communication with both 3.3 V and 1.8 V host is supported. The SPI mode operates in either 4-wire or 3-wire. See the Si5345/44/42 Rev D Family Reference Manual for details.

3.13 Custom Factory Preprogrammed Parts

For applications where a serial interface is not available for programming the device, custom pre-programmed parts can be ordered with a specific configuration written into NVM. A factory preprogrammed part will generate clocks at power-up. Custom, factory-preprogrammed devices are available. The ClockBuilder Pro software can be used to quickly and easily generate a custom part number for your configuration.

In less than three minutes, you will be able to generate a custom part number with a detailed data sheet addendum matching your design's configuration. Once you receive the confirmation email with the data sheet addendum, simply place an order with your local Silicon Labs sales representative. Samples of your preprogrammed device will typically ship in about two weeks.

3.14 Enabling Features and/or Configuration Settings Unavailable in ClockBuilder Pro for Factory Preprogrammed Devices

As with essentially all modern software utilities, the ClockBuilder Pro software is continually being updated and enhanced. By registering at www.silabs.com, you will be notified about changes and their impact. This update process will ultimately enable ClockBuilder Pro software users to access all features and register setting values documented in this data sheet and the Si5345/44/42 Rev D Family Reference Manual.

However, if you must enable or access a feature or register setting value so that the device starts up with this feature or a register setting, but the feature or register setting is not yet available in CBPro, you must contact a Silicon Labs applications engineer for assistance. One example of this type of feature or custom setting is the customizable output amplitude and common voltages for the clock outputs. After careful review of your project file and requirements, the Silicon Labs applications engineer will email back your CBPro project file with your specific features and register settings enabled using what's referred to as the manual "settings override" feature of CBPro. "Override" settings to match your request(s) will be listed in your design report file. Examples of setting "overrides" in a CBPro design report are shown in the following table.

Table 3.3. Setting Overrides

Location	Name	Туре	Target	Dec Value	Hex Value
0x04535[0]	FORCE_HOLD	No NVM	N/A	1	0x1
0x0B48[0:4]	OOF_DIV_CLK_DIS	User	OPN&EVB	0	0x00

Once you receive the updated design file, simply open it in CBPro. The device will begin operation after startup with the values in the NVM file. The flowchart for this process is shown in the following figure.



Figure 3.16. Process for Requesting Non-Standard CBPro Features

Note: Contact Silicon Labs Technical Support at www.silabs.com/support/Pages/default.aspx.

4. Register Map

Refer to the Si5345/44/42 Rev D Family Reference Manual for a complete list of register descriptions and settings.

5. Electrical Specifications

Table 5.1. Recommended Operating Conditions¹

 V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3 V ±5%, T_A = –40 to 85 $^\circ C$

Parameter	Symbol	Min	Тур	Мах	Unit
Ambient Temperature	T _A	-40	25	85	°C
Junction Temperature	TJ _{MAX}	_	_	125	°C
Core Supply Voltage	V _{DD}	1.71	1.80	1.89	V
	V _{DDA}	3.14	3.30	3.47	V
		3.14	3.30	3.47	V
Clock Output Driver Supply Voltage	V _{DDO}	2.37	2.50	2.62	V
		1.71	1.80	1.89	V
Status Pin Supply Voltage	V _{DDS}	3.14	3.30	3.47	V
	• DDS	1.71	1.80	1.89	V

Note:

1. All minimum and maximum specifications are guaranteed and apply across the recommended operating conditions. Typical values apply at nominal supply voltages and an operating temperature of 25 °C unless otherwise noted.

Table 5.2. DC Characteristics

V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3 V ±5%, V_{DDO} = 1.8 V ±5%, 2.5 V ±5%, or 3.3 V ±5%, T_A = -40 to 85 °C

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Orana Oranaka Orana at ¹ 2 3	I _{DD}		—	135	260	mA	
Core Supply Current ^{1, 2, 3}	I _{DDA}		_	120	130	mA	
		LVPECL Output ⁴		22	26	mA	
		@ 156.25 MHz	—	22	20		
		LVDS Output ⁴		15	18	mA	
		@ 156.25 MHz	—	15	10		
Output Buffer Supply Current		3.3 V LVCMOS Output ⁵		22	30	mA	
Output Burier Supply Current	I _{DDOx}	@ 156.25 MHz	—	22			
		2.5 V LVCMOS Output ⁵		18	23	mA	
		@ 156.25 MHz	—	10	25		
		1.8 V LVCMOS Output ⁵		12	16	mA	
		@ 156.25 MHz	—	12	10		
		Si5345 ¹	_	900	1200	mW	
Total Power Dissipation ⁶	Pd	Si5344 ²	_	730	1000	mW	
		Si5342 ³	_	670	950	mW	

Notes:

1. Si5345 test configuration: 7 x 2.5 V LVDS outputs enabled at 156.25 MHz. Excludes power in termination resistors.

2. Si5344 test configuration: 4 x 2.5 V LVDS outputs enabled at 156.25 MHz. Excludes power in termination resistors.

3. Si5342 test configuration: 2 x 2.5 V LVDS outputs enabled at 156.25 MHz. Excludes power in termination resistors.

- 4. Differential outputs terminated into an AC-coupled 100 Ω load.
- 5. LVCMOS outputs measured into a 5-inch 50 Ω PCB trace with 4.7 pF load. The LVCMOS outputs were set to OUTx_CMOS_DRV = 3, which is the strongest driver setting. Refer to the Si5345/44/42 Rev D Family Reference Manual for more details on register settings.



LVCMOS Output Test Configuration



6. Detailed power consumption for any configuration can be estimated using ClockBuilder Pro when an evaluation board (EVB) is not available. All EVBs support detailed current measurements for any configuration.

Table 5.3. Input Clock Specifications

V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3 V ±5%, T_A = –40 to 85 $^\circ C$

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Standard AC-Coupled Differen	tial or Single-Ended (I	N0/IN0b, IN1/IN1b, IN2/IN2b, IN	N3/IN3b, FE	B_IN/FB_IN	lb)	
		Differential	0.008	_	750	MHz
Input Frequency Range	f _{IN}	All Single-ended signals	0.008		250	MHz
		(including LVCMOS)	0.008	_	250	IVITIZ
		Differential AC-coupled	100		1800	m\/nn00
		f _{IN} < 250 MHz	100	_	1800	mVpp_se
	Mar	Differential AC-coupled	225		1900	m) (nn
Voltage Swing ¹	V _{IN}	250 MHz < f _{IN} < 750 MHz	225	_	1800	mVpp_se
		Single-ended AC-coupled	100			
		f _{IN} < 250 MHz	100	_	3600	mVpp_se
Slew Rate ^{2, 3}	SR		400	_		V/µs
Duty Cycle	DC		40	_	60	%
Input Capacitance	C _{IN}			2.4	_	pF
Input Resistance Differential	R _{IN_DIFF}		_	16		kΩ
Input Resistance Single-Ended	R _{IN_SE}		_	8	_	kΩ
LVCMOS / Pulsed CMOS, DC-C	oupled, Single-Ended	(IN0, IN1, IN2, IN3, FB_IN) ³				
	f _{IN_LVCMOS}		0.008	_	250	MHz
Input Frequency	f _{IN_PULSED_CMOS}		0.008	_	1.0	MHz
	V _{IL}		-0.2	_	0.4	V
Input Voltage	V _{IH}		0.8			V
Slew Rate ^{2, 3}	SR		400	_		V/µs
Minimum Pulse Width	PW	Pulse Input	1.6		_	ns
Input Resistance	R _{IN}			8	_	kΩ
REFCLK (Applied to XA/XB)						
		Full operating range. Jitter performance may be re- duced.	24.97	_	54.06	MHz
REFCLK Frequency	f _{IN_REF}	Range for best jitter.	48	_	54	MHz
		TCXO frequency for SyncE applications. Jitter perform- ance may be reduced.		40	_	MHz
Input Single-ended Voltage Swing	V _{IN_SE}		365	_	2000	mVpp_se
Input Differential Voltage Swing	V _{IN_DIFF}		365		2500	mVpp_diff
Slew Rate ^{2, 3}	SR		400	_	_	V/µs

Parameter	Symt	Symbol Test Condition		Min	Тур	Max	Unit
Input Duty Cycle	DC	;		40	_	60	%
	fied as single-ended	d mVpp.	− ↓ Vpp_diff = 2*Vpp_se				
•		•	erformance could degrade if lanual for more information.)		m slew rate	e specificati	on is not
3. Rise and fall times ca	be estimated using	the following	g simplified equation: tr/tf ₈₀₋₂	= ((0.8 –	0.2) x V _{IN \}	/pp_se) / SR	. Pulsed

S. Rise and fail times can be estimated using the following simplified equation. $I/I_{80-20} = ((0.6 - 0.2) \times V_{IN_Vpp_se})$ / SR. Pulsed CMOS mode is intended primarily for single-ended LVCMOS input clocks ≤ 1 MHz that must be dc-coupled because they have a duty cycle significantly less than 50%. A typical application example is a low-frequency video frame sync pulse. Since the input thresholds (V_{IL}, V_{IH}) of this buffer are non-standard (0.4 and 0.8 V, respectively) refer to the input attenuator circuit for dc-coupled pulsed LVCMOS in the Si5345/44/42 Rev D Family Reference Manual. Otherwise, for standard LVCMOS input clocks, use the Standard Differential or Single-Ended ac-coupled input mode.

Table 5.4. Control Input Pin Specifications

 V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3 V ±5%, V_{DDS} = 3.3 V ±5%, 1.8 V ±5%, T_A = -40 to 85 °C

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Si5345 Control Input Pins(I2C_SEL, IN_SEL[1	:0], RSTb, OEb, A1, SCLK, A	A0/CSb, FINC	, FDEC, SDA	/SDIO)	
	V _{IL}		_	_	0.3 × V _{DDIO} 1	V
Input Voltage	V _{IH}		0.7 × V _{DDIO} ¹	_	_	V
Input Capacitance	C _{IN}		_	1.5	_	pF
Input Resistance	R _{IN}		_	20	_	kΩ
Minimum Pulse Width	PW	RSTb, FINC and FDEC	100	_	_	ns
Update Rate	T _{UR}	FINC and FDEC	1	_	_	μs
Si5344/42 Control Input Pin	s (I2C_SEL, IN_SE	L[1:0], RSTb, OEb, A1, SCL	K, A0/CSb, SI	DA/SDIO)		
	V _{IL}		_	_	0.3 × V _{DDIO} 1	V
Input Voltage	V _{IH}		0.7 × V _{DDIO} 1	_	_	V
Input Capacitance	C _{IN}		_	1.5	_	pF
Input Resistance	R _{IN}		_	20	_	kΩ
Minimum Pulse Width	PW	RSTb	100	_	_	ns
Note:	1	1		1	1	

Note:

1. V_{DDIO} is determined by the IO_VDD_SEL bit. It is selectable as V_{DDA} or V_{DD}. See the Si5345/44/42 Rev D Family Reference Manual for more details on the proper register settings.

Table 5.5. Differential Clock Output Specifications

V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3 V ±5%, V_{DDO} = 1.8 V ±5%, 2.5 V ±5%, or 3.3 V ±5%, T_A = -40 to 85 °C

Parameter	Symbol	Test Con	dition	Min	Тур	Max	Unit	
Si5345/44/42								
				0.0001	_	720	MHz	
	fout	MultiSynth not used		733.33		800.00	MHz	
Output Frequency				825	_	1028	MHz	
		MultiSynt	h used	0.0001	—	720	MHz	
		f _{OUT} < 40	0 MHz	48	—	52	%	
Duty Cycle	DC	400 MHz < f _C MH:		45	_	55	%	
Output-Output Skew Using Same MultiSynth	T _{SKS}	Outputs on same MultiSynth (Measured at 712.5 MHz)		_	0	75	ps	
OUT-OUTb Skew	TSK_OUT	Measured from to negative o	the positive		0	50	ps	
o	VOUT	V _{DDO} = 3.3 V, 2.5 V, 1.8 V	LVDS	350	430	510	mVpp_se	
Output Voltage Swing ¹	1001	V _{DDO} = 3.3 V, 2.5 V	LVPECL	640	750	900	mVpp_se	
		Va	V _{DDO} = 3.3 V	LVDS	1.10	1.2	1.3	V
Common Mode Voltage ^{1, 2}		VDDO - 0.0 V	LVPECL	1.90	2.0	2.1	V	
(100 Ω load line-to-line)	VCM	V _{DDO} = 2.5 V	LVPECL LVDS	1.1	1.2	1.3	V	
		V _{DDO} = 1.8 V	sub-LVDS	0.8	0.9	1.0	V	
Rise and Fall Times (20% to 80%)	tR/tF			_	100	150	ps	
Differential Output Impedance	ZO			_	100	_	Ω	
		10 kHz sinus	oidal noise	_	-101	_	dBc	
Power Supply Noise Rejec-	PSRR	100 kHz sinus	oidal noise	—	-96	_	dBc	
tion ²	FOKK	500 kHz sinusoidal noise		—	-99	_	dBc	
		1 MHz sinuso	oidal noise	_	-97	_	dBc	
Output-output Crosstalk ³	XTALK	Si534	45		-72		dBc	
	ATALK	Si5342	2/44		-88	_	dBc	

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Notes:						
than the TIA/EIA-644 maxim Not all combinations of volta	ed independent num. Refer to th age amplitude an Vpp_se	gs are programmable through ly. Note that the maximum LV e Si5345/44/42 Rev D Family nd common mode voltages se	DS single-enc Reference Ma ttings are pos	led amplitude anual for more	can be up to	110 mV higher
2. Measured for 156.25 MHz c ured.	↓ Vpp_se) = 3.3 V and	noise spur ar	nplitude meas-

3. Measured across two adjacent outputs, both in LVDS mode, with the victim running at 155.52 MHz and the aggressor at 156.25 MHz. Refer to "AN862: Optimizing Si534x Jitter Performance in Next Generation Internet Infrastructure Systems" for guidance on crosstalk optimization. Note that all active outputs must be terminated when measuring crosstalk.

Table 5.6. LVCMOS Clock Output Specifications

V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3 V ±5%, V_{DDO} = 1.8 V ±5%, 2.5 V ±5%, or 3.3 V ±5%, T_A = -40 to 85 °C

Parameter	Symbol	Test Condit	ion	Min	Тур	Max	Unit	
Output Frequency	f _{OUT}			0.0001	_	250	MHz	
Dute Ousla	50	f _{OUT} <100 MHz		48	_	52	%	
Duty Cycle	DC	100 MHz < f _{OUT} <	250 MHz	45	_	55	%	
		V _{DDO} = 3.3 V						
		OUTx_CMOS_DRV = 1	I _{OH} = -10 mA	V _{DDO} x 0.85		_	V	
		OUTx_CMOS_DRV = 2	I _{OH} = –12 mA	V _{DDO} x 0.85	_	_	V	
		OUTx_CMOS_DRV = 3	I _{OH} = –17 mA	V _{DDO} x 0.85	_	_	V	
			V	_{DDO} = 2.5 V				
Output Voltage High ^{1, 2, 3}	V _{OH}	OUTx_CMOS_DRV = 1	I _{OH} = –6 mA	V _{DDO} x 0.85	_	_	V	
		OUTx_CMOS_DRV = 2	I _{OH} = –8 mA	V _{DDO} x 0.85	—	_	V	
		OUTx_CMOS_DRV = 3	I _{OH} = –11 mA	V _{DDO} x 0.85	_	_	V	
		V _{DDO} = 1.8 V						
		OUTx_CMOS_DRV = 2	I _{OH} = –4 mA	V _{DDO} x 0.85	_	_	V	
		OUTx_CMOS_DRV = 3	I _{OH} = –5 mA	V _{DDO} x 0.85	_	_	V	
		V _{DDO} = 3.3 V						
		OUTx_CMOS_DRV = 1	I _{OL} = 10 mA	_	_	V _{DDO} x 0.15	V	
		OUTx_CMOS_DRV = 2	I _{OL} = 12 mA	_	_	V _{DDO} x 0.15	V	
		OUTx_CMOS_DRV = 3	I _{OL} = 17 mA		_	V _{DDO} x 0.15	V	
		V _{DDO} = 2.5 V						
Output Voltage Low ^{1, 2, 3}	V _{OL}	OUTx_CMOS_DRV = 1	I _{OL} = 6 mA		_	V _{DDO} x 0.15	V	
		OUTx_CMOS_DRV = 2	I _{OL} = 8 mA	_	_	V _{DDO} x 0.15	V	
		OUTx_CMOS_DRV = 3	I _{OL} = 11 mA	_	_	V _{DDO} x 0.15	V	
		V _{DDO} = 1.8 V						
		OUTx_CMOS_DRV = 2	I _{OL} = 4 mA	_	_	V _{DDO} x 0.15	V	
		OUTx_CMOS_DRV = 3	I _{OL} = 5 mA	_	_	V _{DDO} x 0.15	V	
LVCMOS Rise and Fall		V _{DDO} = 3.3	V		400	600	ps	
Times ³	tr/tf	V _{DDO} = 2.5	V	_	450	600	ps	
(20% to 80%)		V _{DDO} = 1.8	V	_	550	750	ps	



Table 5.7. Output Status Pin Specifications

V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3 V ±5%, V_{DDS} = 3.3 V ±5%, 1.8 V ±5%, T_A = –40 to 85 $^\circ C$

Parameter	Symbol	Test Condition Min Typ		Мах	Unit	
Si5345 Status Output Pins (L	OLb, INTRb, SDA	SDIO ¹ , SDO)				
Output Voltage	V _{OH}	I _{OH} = -2 mA	$I_{OH} = -2 \text{ mA}$ $V_{DDIO}^2 x$ 0.85		_	V
	V _{OL}	I _{OL} = 2 mA —		_	V _{DDIO} ² x 0.15	V
Si5344/42 Status Output Pins	s (INTRb, SDA/SDI	01 ¹ , SDO)			·	
Output Voltage	V _{OH}	$I_{OH} = -2 \text{ mA}$ $V_{DDIO}^2 = 0.85$		_	_	V
	V _{OL}	I _{OL} = 2 mA		_	V _{DDIO} ² x 0.15	V
Si5344 Status Output Pins (L	OLb, LOS_XAXB)	1		1 1	
Si5342 Status Output Pins (L	OLb, LOS_XAXB	o, LOS0b, LOS1b, LOS2b,	LOS3b)			
	V _{OH}	I _{OH} = –2 mA	V _{DDS} x 0.85	_	_	V
Output Voltage	V _{OL}	I _{OL} = 2 mA	_	_	V _{DDS} x 0.15	V
Notes:		I				
1. The V _{OH} specification doe with I2C_SEL pulled high.			when the seria	I interface is	in I ² C mode or i	s unused
2. V_{DDIO} is determined by the	e IO_VDD_SEL bit.	It is selectable as V_{DDA} or V_{DDA}	√ _{DD} . See the <mark>S</mark> i	5345/44/42 F	Rev D Family Re	ference

Manual for more details on the proper register settings.

Table 5.8. Performance Characteristics

V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3 V ±5%, T_A = –40 to 85 $^\circ C$

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
PLL Loop Bandwidth Program- ming Range ¹	f _{BW}		0.1	_	4000	Hz
Initial Start-Up Time	t START	Time from power-up to when the device generates free-running clocks	_	30	45	ms
PLL Lock Time ²	t _{ACQ}	f _{IN} = 19.44 MHz		280	300	ms
POR to Serial Interface Ready ³	t _{RDY}		_	_	15	ms
Jitter Peaking	J _{PK}	Measured with a frequency plan run- ning a 25 MHz input, 25 MHz output, and a Loop Bandwidth of 4 Hz	_	_	0.1	dB
Jitter Tolerance	J _{TOL}	Compliant with G.8262 Options 1 and 2 Carrier Frequency = 10.3125 GHz Jitter Modulation Frequency = 10 Hz	_	3180	_	UI pk-pk
Maximum Phase Transient During a Hitless Switch	tswitch	Manual or automatic switch between two input clocks at same frequency ⁵	_	_	2.0	ns
Pull-in Range	ω _P			500		ppm
Zero-Delay Mode Input-to-Output Delay	tzdelay	Delay between reference and feedback input with both clocks at 10 MHz and same slew rate. Ref clock rise time must be <200 ps. ⁶	_	110		ps
	I	Integer Mode 12 kHz to 20 MHz	_	90	145	fs rms
RMS Phase Jitter ⁴	J _{GEN}	Fractional Mode 12 kHz to 20 MHz	_	120	170	fs rms

Note:

1. Actual loop bandwidth might be lower; please refer to CBPro for actual value for your frequency plan.

2. Lock Time can vary significantly depending on several parameters, such as bandwidths, LOL tresholds, etc. For this case, lock time was measured with nominal and fastlock bandwidths set to 100 Hz, LOL set/clear thresholds of 6/0.6 ppm respectively, using INO as clock reference by removing the reference and enabling it again, then measuring the delta time between the first rising edge of the clock reference and the LOL indicator deassertion.

3. Measured as time from valid VDD/VDDA rails (90% of their value) to when the serial interface is ready to respond to commands.

4. Jitter generation test conditions: f_{IN} = 19.44 MHz, f_{OUT} = 156.25 MHz LVPECL, loop bandwidth = 100 Hz, F_{XTAL} = 48 MHz.

5. For input frequency configurations that have Fpfd > 1 MHz, consult your CBPro design report for the Fpfd frequency of your configuration.

6. Delay is dependent on frequency configuration. Using Fpfd < 64 kHz will result in higher delay values.

			Standard Mode		Fast Mode			
Parameter	Symbol	Test Condition	100	100 kbps		400 kbps		
			Min	Мах	Min	Max		
SCL Clock Frequency	f _{SCL}		_	100	_	400	kHz	
SMBus Timeout	_	When Timeout is Enabled	25	35	25	35	ms	
Hold time (Repeated) START condition	t _{HD:STA}		4.0	_	0.6	_	μs	
Low Period of the SCL Clock	t _{LOW}		4.7	_	1.3		μs	
HIGH Period of the SCL Clock	thigh		4.0	_	0.6	_	μs	
Setup Time for a Repeated START Condition	t _{SU:STA}		4.7	_	0.6		μs	
Data Hold Time	t _{HD:DAT}		100	—	100		ns	
Data Setup Time	t _{SU:DAT}		250	—	100		ns	
Rise Time of both SDA and SCL Signals	t _r		_	1000	20	300	ns	
Fall Time of both SDA and SCL Signals	t _f		_	300		300	ns	
Setup Time for STOP Condi- tion	tsu:sto		4.0	_	0.6	_	μs	
Bus Free Time between a STOP and START Condition	t _{BUF}		4.7	_	1.3	_	μs	
Data Valid Time	t _{VD:DAT}			3.45		0.9	μs	
Data Valid Acknowledge Time	t _{VD:ACK}		_	3.45		0.9	μs	

Table 5.9. I²C Timing Specifications (SCL,SDA)



Figure 5.1. I²C Serial Port Timing Standard and Fast Modes

Table 5.10. SPI Timing Specifications (4-Wire)

V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3V ±5%, T_A = –40 to 85 $^\circ C$

Parameter	Symbol	Min	Тур	Мах	Unit
SCLK Frequency	f _{SPI}	_	_	20	MHz
SCLK Duty Cycle	T _{DC}	40	_	60	%
SCLK Period	T _C	50	_	_	ns
Delay Time, SCLK Fall to SDO Active	T _{D1}	_	12.5	18	ns
Delay Time, SCLK Fall to SDO	T _{D2}	_	10	15	ns
Delay Time, CSb Rise to SDO Tri-State	T _{D3}	_	10	15	ns
Setup Time, CSb to SCLK	T _{SU1}	5	_	_	ns
Hold Time, SCLK Fall to CSb	T _{H1}	5	_	_	ns
Setup Time, SDI to SCLK Rise	T _{SU2}	5	_	_	ns
Hold Time, SDI to SCLK Rise	T _{H2}	5	_	_	ns
Delay Time Between Chip Selects (CSb)	T _{CS}	2	_		T _C



Figure 5.2.	4-Wire S	PI Serial	Interface	Timing
-------------	----------	-----------	-----------	--------

Table 5.11. SPI Timing Specifications (3-Wire)

V_{DD} = 1.8 V ±5%, V_{DDA} = 3.3V ±5%, T_A = –40 to 85 $^\circ C$

Parameter	Symbol	Min	Тур	Мах	Unit
SCLK Frequency	f _{SPI}	—	_	20	MHz
SCLK Duty Cycle	T _{DC}	40	_	60	%
SCLK Period	T _C	50	_	_	ns
Delay Time, SCLK Fall to SDIO Turn-on	T _{D1}	_	12.5	20	ns
Delay Time, SCLK Fall to SDIO Next-bit	T _{D2}	_	10	15	ns
Delay Time, CSb Rise to SDIO Tri-State	T _{D3}	_	10	15	ns
Setup Time, CSb to SCLK	T _{SU1}	5	_		ns
Hold Time, CSb to SCLK Fall	T _{H1}	5	_	_	ns
Setup Time, SDI to SCLK Rise	T _{SU2}	5	_	_	ns
Hold Time, SDI to SCLK Rise	T _{H2}	5	—	—	ns
Delay Time Between Chip Selects (CSb)	T _{CS}	2	_	_	T _C



Figure 5.3.	3_Wiro	SDI	Sorial	Intorfaco	Timina		
Figure 5.5.	2-AAUG	SFI	Serial	internace	riining		
Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit	
------------------------------	-------------------	---	-------	-----	-------	------	--
Crystal Frequency Range	f _{XTAL}	Full operating range. Jit- ter performance may be reduced.	24.97	_	54.06	MHz	
		Range for best jitter.	48		54	MHz	
Load Capacitance	CL		—	8	_	pF	
Crystal Drive Level	dL		_	_	200	μW	
Equivalent Series Resistance	r _{ESR}	Refer to the Si5345-44-42 Family Reference Manual to determine ESR and shun					
Shunt Capacitance	C _O	capacitance.					

Table 5.12. Crystal Specifications

Note:

1. Refer to the Si534x/8x Jitter Attenuators Recommended Crystal, TCXO and OCXOs Reference Manual for recommended 48 to 54 MHz crystals. The Si5345/44/42 are designed to work with crystals that meet these specifications.

Table 5.13. Thermal Characteristics

Parameter	Symbol	Test Condition ¹	Value	Unit
Si5345-64QFN				
Thormal Desistance		Still Air	22	°C/W
hermal Resistance	θ _{JA}	Air Flow 1 m/s	19.4	°C/W
Junction to Ambient		Air Flow 2 m/s	18.3	°C/W
Thermal Resistance	θ _{JC}		9.5	°C/W
Junction to Case	OJC		9.5	C/W
Thermal Resistance	θ _{JB}		9.4	°C/W
Junction to Board	Ψ_{JB}		9.3	°C/W
Thermal Resistance				00.004
Junction to Top Center	Ψ_{JT}		0.2	°C/W
Si5344, Si5342-44QFN				
Thermal Resistance		Still Air	22.3	°C/W
	θ _{JA}	Air Flow 1 m/s	19.4	°C/W
Junction to Ambient		Air Flow 2 m/s	18.4	°C/W
Thermal Resistance	0		10.0	°C/W
Junction to Case	θ _{JC}		10.9	C/W
Thermal Resistance	θ _{JB}		9.3	°C/W
Junction to Board	Ψ _{JB}		9.2	°C/W
Thermal Resistance				
Junction to Top Center	Ψ_{JT}		0.23	°C/W

Si5345/44/42 Rev D Data Sheet Electrical Specifications

Note:							
1. Based on PCB Dimension: 3" x 4.5" PCB Thickness: 1.6 mm, PCB Land/Via: 36, Number of Cu Layers: 4							

Table 5.14. Absolute Maximum Ratings ^{1, 2, 3}

Parameter	Symbol	Test Condition	Value	Unit
	V _{DD}		-0.5 to 3.8	V
	V _{DDA}		-0.5 to 3.8	V
DC Supply Voltage	V _{DDO}		-0.5 to 3.8	V
	V _{DDS}		-0.5 to 3.8	V
	V _{I1} ⁴	IN0-IN3/FB_IN	-1.0 to 3.8	V
Input Voltage Range	V ₁₂	IN_SEL1, IN_SEL0, RSTb, OEb, I2C_SEL, FINC, FDEC, SDI, SCLK, A0/CSb, A1, SDA/SDIO	-0.5 to 3.8	V
	V _{I3}	XA/XB	-0.5 to 2.7	V
Latch-up Tolerance	LU		JESD78 (Compliant
ESD Tolerance	HBM	100 pF, 1.5 kΩ	2.0	kV
Storage Temperature Range	T _{STG}		–55 to 150	°C
Maximum Junction Temperature in Operation	T _{JCT}		125	°C
Soldering Temperature	т		000	*0
(Pb-free profile) ⁵	T _{PEAK}		260	°C
Soldering Temperature Time at T _{PEAK} (Pb-free profile) ⁵	T _P		20–40	S

Note:

1. Permanent device damage may occur if the absolute maximum ratings are exceeded. Functional operation should be restricted to the conditions as specified in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2.64-QFN and 44-QFN packages are RoHS-6 compliant.

3. Moisture sensitivity level is MSL2. For more packaging information, go to the Silicon Labs RoHS information page.

4. The minimum voltage at these pins can be as low as –1.0 V when an ac input signal of 8 kHz or greater is applied. See Table 5.3 Input Clock Specifications on page 26 for single-ended ac-coupled f_{IN} < 250 MHz.

5. The device is compliant with JEDEC J-STD-020.

6. Typical Application Schematic



Figure 6.1. 10G Ethernet Data Center Switch and Compute Blade Schematic



Figure 6.2. Sync E Line Card

7. Detailed Block Diagrams







Figure 7.2. Si5344 Block Diagram



Figure 7.3. Si5342 Block Diagram

8. Typical Operating Characteristics



The phase noise plots below were taken under the following conditions: V_{DD} = 1.8 V; V_{DDA} = 3.3 V; V_{DDS} = 3.3 V, 1.8 V; T_A = 25 °C.

Figure 8.1. Input = 25 MHz; Output = 625 MHz, 2.5 V LVDS



Figure 8.2. Input = 25 MHz; Output = 156.25 MHz, 2.5 V LVDS



Figure 8.3. Input = 25 MHz; Output = 155.52 MHz, 2.5 V LVDS

9. Pin Descriptions





Pin Name		Pin Number		Din Tural	Function
Pin Name	Si5345	Si5344	Si5342	Pin Type ¹	Function
Inputs					
ХА	8	5	5	I	Crystal Input. Input pins for external crystal (XTAL). Alternatively
ХВ	9	6	6	I	these pins can be driven with an external reference clock (REFCLK). An internal register bit selects XTAL or REFCLK mode. Default is XTAL mode.
X1	7	4	4	I	XTAL Shield. Connect these pins directly to the XTAL ground
X2	10	7	7	I	pins. X1, X2 and the XTAL ground pins should be separated from the PCB ground plane. Refer to the Si5345/44/42 Rev D Family Reference Manual for layout guidelines. These pins should be left disconnected when connecting XA/XB pins to an external refer- ence clock (REFCLK).
IN0	63	43	43	I	
IN0b	64	44	44	I	Clock Inputs. These pins accept an input clock for synchronizing the device. They support both differential and single-ended clock
IN1	1	1	1	I	signals. Refer to 3.7.6 Input Configuration and Terminations for input termination options. These pins are high-impedance and
IN1b	2	2	2	I	must be terminated externally. The negative side of the differen-
IN2	14	10	10	I	tial input must be grounded through a capacitor when accepting a single-ended clock.
IN2b	15	11	11	I	
IN3/FB_IN	61	41	41	I	Clock Input 3/External Feedback Input. By default these pins
IN3b/FB_INb	62	42	42	I	are used as the fourth clock input (IN3/IN3b). They can also be used as the external feedback input (FB_IN/FB_INb) for the op- tional zero delay mode. See 3.9.12 Zero Delay Mode for details on the optional zero delay mode.

Table 9.1. Si5345/44/42 Pin Descriptions

		Pin Number			
Pin Name	Si5345	Si5344	Si5342	 Pin Type¹ 	Function
Outputs			1		
OUT0	24	20	20	0	
OUT0b	23	19	19	0	
OUT1	28	25	25	0	
OUT1b	27	24	24	0	
OUT2	31	31	_	0	
OUT2b	30	30	_	0	
OUT3	35	36	_	0	
OUT3b	34	35	_	0	
OUT4	38	_	_	0	Output Clocks. These output clocks support a programmable
OUT4b	37	_	_	0	signal swing and common mode voltage. Desired output signal format is configurable using register control. Termination recom-
OUT5	42	_	_	0	mendations are provided in 3.9.3 Differential Output Terminations and 3.9.4 LVCMOS Output Terminations. Unused outputs should
OUT5b	41	_	_	0	be left unconnected.
OUT6	45	_	_	0	
OUT6b	44	_	_	0	
OUT7	51	_	_	0	
OUT7b	50	_	_	0	
OUT8	54	_	_	0	
OUT8b	53	_	—	0	
OUT9	59	_	_	0	
OUT9b	58	_	_	0	
Serial Interfac	ce		·		
I2C_SEL	39	38	38	I	I ² C Select ² . This pin selects the serial interface mode as I ² C (I2C_SEL = 1) or SPI (I2C_SEL = 0). This pin is internally pulled up by a ~ 20 kΩ resistor to the voltage selected by the IO_VDD_SEL register bit.
SDA/SDIO	18	13	13	I/O	Serial Data Interface ² This is the bidirectional data pin (SDA) for the I ² C mode, or the bidirectional data pin (SDIO) in the 3-wire SPI mode, or the input data pin (SDI) in 4-wire SPI mode. When in I ² C mode, this pin must be pulled-up using an external resistor of at least 1 k Ω . No pull-up resistor is needed when is SPI mode. Tie low when un- used.

Table 9.2. Si5345/44/42 Pin Descriptions

		Pin Number		1	
Pin Name	Si5345	Si5344	Si5342	Pin Type ¹	Function
					Address Select 1/Serial Data Output ²
A1/SDO	17	15	15	I/O	In I ² C mode, this pin functions as the A1 address input pin and does not have an internal pull-up or pull-down resistor. In 4-wire SPI mode this is the serial data output (SDO) pin and drives high to the voltage selected by the IO_VDD_SEL bit. Leave disconnected when unused.
SCLK	16	14	14	I	Serial Clock Input ² This pin functions as the serial clock input for both I ² C and SPI modes. When in I ² C mode, this pin must be pulled-up using an external resistor of at least 1 k Ω . No pull-up resistor is needed when in SPI mode. Tie high or low when unused.
					Address Select 0/Chip Select ²
A0/CSb	19	16	16	I	This pin functions as the hardware controlled address A0 in I ² C mode. In SPI mode, this pin functions as the chip select input (active low). This pin is internally pulled-up by a ~20 k Ω resistor and can be left unconnected when not in use.
Control/Status	5				
					Interrupt ²
INTRb	12	33	33	0	This pin is asserted low when a change in device status has oc- curred. It should be left unconnected when not in use.
RSTb	6	17	17	I	Device Reset² Active low input that performs power-on reset (POR) of the device. Resets all internal logic to a known state and forces the device registers to their default values. Clock outputs are disabled during reset. This pin is internally pulled-up and can be left unconnected when not in use.
					Output Enable ²
OEb	11	12	12	I	This pin disables all outputs when held high. This pin is internally pulled low and can be left unconnected when not in use.
					Loss Of Lock (Si5345) ²
LOLb -	47	_	_	0	This output pin indicates when the DSPLL is locked (high) or out- of-lock (low). It can be left unconnected when not in use.
					Loss Of Lock (Si5344/42) ³
	—	27	27	0	This output pin indicates when the DSPLL is locked (high) or out- of-lock (low). It can be left unconnected when not in use.
LOSOb			30	0	Loss Of Signal for IN0 ³
LOS0b			30	0	This pin indicate a loss of clock at the IN0 pin when low.
LOS1b			31	0	Loss Of Signal for IN1 ³
LUSID	—		31	0	This pin indicate a loss of clock at the IN1 pin when low.
10825			35	0	Loss Of Signal for IN2 ³
LOS2b		- -	30	0	This pin indicate a loss of clock at the IN2 pin when low.

Pin Name	Si5345	Pin Number Si5344	Si5342	Pin Type ¹	Function
LOS3b	_	_	36	0	Loss Of Signal for IN3 ³
20000			00	Ū	This pin indicate a loss of clock at the IN3 pin when low.
		28	28	0	Loss Of Signal on XA/XB Pins ³
LOS_XAXBb	—	20	20	0	This pin indicates a loss of signal at the XA/XB pins when low.
					Frequency Increment Pin ²
FINC	48	_	_	I	This pin is used to step-up the output frequency of a selected out- put. The affected output and its frequency change step size is register configurable. This pin is internally pulled low and can be left unconnected when not in use.
					Frequency Decrement Pin ²
FDEC	25	_	_	I	This pin is used to step-down the output frequency of a selected output. The affected output driver and its frequency change step size is register configurable. This pin is internally pulled low and can be left unconnected when not in use.
IN_SEL0	3	3	3	I	Input Reference Select ²
IN_SEL1	4	37	37	I	The IN_SEL[1:0] pins are used in manual pin controlled mode to select the active clock input as shown in Table 3.1 Manual Input Selection Using IN_SEL[1:0] Pins on page 10. These pins are internally pulled low.
	5	_	_	_	
	20	_	_		
RSVD	21	_	_		Reserved
	55	_	_		These pins are connected to the die. Leave disconnected.
	56	_	_		
					No Connect
NC	_	22	22		These pins are not connected to the die. Leave disconnected.
Power					
	32	21	21	Р	Core Supply Voltage
	46	32	32	Р	The device operates from a 1.8 V supply. A 1.0 μF bypass capac-
VDD	60	39	39	Р	itor should be placed very close to this pin. See the Si5345/44/42 Rev D Family Reference Manual for power supply filtering recom-
	_	40	40	Р	mendations.
	13	8	8	Р	Core Supply Voltage 3.3 V
VDDA	_	9	9	Р	This core supply pin requires a 3.3 V power source. A 1 μ F by- pass capacitor should be placed very close to this pin. See the Si5345/44/42 Rev D Family Reference Manual for power supply filtering recommendations.
	_	26	26	Р	Status Output Voltage
VDDS	_	_	29	Р	The voltage on this pin determines VOL/VOH on the Si5342/44
	_		34	Р	LOL_A and LOL_B outputs. Connect to either 3.3 V or 1.8 V. A 1.0 μ F bypass capacitor should be placed very close to this pin.

Pin Name		Pin Number		Pin Type ¹	Function
Pin Name	Si5345	Si5344	Si5342	Pin Type.	Function
VDDO0	22	18	18	Р	
VDDO1	26	23	23	Р	
VDDO2	29	29	_	Р	
VDDO3	33	34	_	Р	Output Clock Supply Voltage
VDDO4	36	_	_	Р	Supply voltage (3.3 V, 2.5 V, 1.8 V) for OUTn, OUTn outputs. For
VDDO5	40	_	_	Р	unused outputs, leave VDDO pins unconnected. An alternative option is to connect the VDDO pin to a power supply and disable
VDDO6	43	_		Р	the output driver to minimize current consumption.
VDD07	49	_		Р	
VDDO8	52	_	_	Р	
VDDO9	57	_		Р	
GND PAD	_	_		Р	Ground Pad This pad provides connection to ground and must be connected for proper operation. Use as many vias as practical, and keep the via length to an internal ground plane as short as possible.

Note:

1. I = Input, O = Output, P = Power.

2. The IO_VDD_SEL control bit (0x0943 bit 0) selects 3.3 V or 1.8 V operation.

3. The voltage on the VDDS pin(s) determines 3.3 V or 1.8 V operation.

4. Refer to the Si5345/44/42 Rev D Family Reference Manual for more information on register setting names.

5. All status pins except I^2C and SPI are push-pull.

10. Package Outlines

10.1 Si5345 9x9 mm 64-QFN Package Diagram

The following figure illustrates the package details for the Si5345. The table lists the values for the dimensions shown in the illustration.



Figure 10.1. 64-Pin Quad Flat No-Lead (QFN)

Table 10.1.	Package Dimensions
-------------	--------------------

Dimension	Min	Nom	Мах			
A	0.80	0.85	0.90			
A1	0.00	0.02	0.05			
b	0.18	0.25	0.30			
D		9.00 BSC				
D2	5.10	5.20	5.30			
e	0.50 BSC					
E		9.00 BSC				
E2	5.10	5.20	5.30			
L	0.30	0.40	0.50			
ааа	_	_	0.10			
bbb	_	_	0.10			
ссс	_	_	0.08			
ddd		_	0.10			

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. This drawing conforms to the JEDEC Solid State Outline MO-220.

4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

10.2 Si5344 and Si5342 7x7 mm 44-QFN Package Diagram

The following figure illustrates the package details for the Si5344 and Si5342. The table lists the values for the dimensions shown in the illustration.



Figure 10.2. 44-Pin Quad Flat No-Lead (QFN)

Dimension	Min	Nom	Мах			
A	0.80	0.85	0.90			
A1	0.00	0.02	0.05			
b	0.18	0.25	0.30			
D	7.00 BSC					
D2	5.10	5.20	5.30			
e	0.50 BSC					
E	7.00 BSC					
E2	5.10	5.20	5.30			
L	0.30	0.40	0.50			
ааа	_	_	0.10			
bbb	_	_	0.10			
CCC	—	_	0.08			
ddd	_	_	0.10			

Table 10.2. Package Dimensions

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. This drawing conforms to the JEDEC Solid State Outline MO-220.

4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

11. PCB Land Pattern

The following figure illustrates the PCB land pattern details for the devices. The table lists the values for the dimensions shown in the illustration.





Table 11.1. PCB Land Pattern Dimensions

Dimension	Si5345 (Max)	Si5344/42 (Max)
C1	8.90	6.90
C2	8.90	6.90
E	0.50	0.50
X1	0.30	0.30
Y1	0.85	0.85
X2	5.30	5.30
Y2	5.30	5.30

Notes:

General

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. This Land Pattern Design is based on the IPC-7351 guidelines.

3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition is calculated based on a fabrication Allowance of 0.05 mm.

Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

Stencil Design

1. A stainless steel, laser-cut and electropolished stencil with trapezoidal walls should be used to assure good solder paste release.

- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
- 4. A 3x3 array of 1.25 mm square openings on 1.80 mm pitch should be used for the center ground pad.

Card Assembly

1. A No-Clean, Type-3 solder paste is recommended.

2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

12. Top Marking





Line	Characters	Description
1	Si534fg-	Base part number and Device Grade for Any-frequency, Any-output, Jitter Cleaning Clock (single PLL):
		f = 5: 10-output Si5345: 64-QFN
		f = 4: 4-output Si5344: 44-QFN
		f = 2: 2-output Si5342: 44-QFN
		g = Device Grade (A, B, C, D). See 2. Ordering Guide for more information.
		– = Dash character.
2	Rxxxx-GM	R = Product revision. (Refer to 2. Ordering Guide for latest revision).
		xxxxx = Customer specific NVM sequence number. Optional NVM code as- signed for custom, factory pre-programmed devices.
		Characters are not included for standard, factory default configured devices. See 2. Ordering Guide for more information.
		-GM = Package (QFN) and temperature range (–40 to +85 °C)
3	YYWWTTTTTT	YYWW = Characters correspond to the year (YY) and work week (WW) of package assembly.
		TTTTTT = Manufacturing trace code.
4	Circle w/ 1.6 mm (64-QFN) or 1.4 mm (44-QFN) diameter	Pin 1 indicator; left-justified
	e4	Pb-free symbol; Center-Justified
	TW	TW = Taiwan; Country of Origin (ISO Abbreviation)

13. Device Errata

Log in or register at www.silabs.com to access the device errata document.

14. Revision History

Revision 1.2

September, 2018

- Updated Figure 3.3 Crystal Resonator and External Reference Clock Connection Options on page 10.
- Updated Figure 3.4 Termination of Differential and LVCMOS Input Signals on page 12.
- Updated Figure 3.13 Supported Differential Output Terminations on page 18.
- Removed Output Skew Control section.
- Updated Table 5.2 DC Characteristics on page 25
 - Updated Note 5 and LVCMOS Output Test Configuration circuit.
- Updated Table 5.3 Input Clock Specifications on page 26.
- Updated Table 5.4 Control Input Pin Specifications on page 27.
 - · Updated Input Capacitance specification.
- Updated Table 5.5 Differential Clock Output Specifications on page 28.
- Updated Table 5.6 LVCMOS Clock Output Specifications on page 30.
 - Updated LVCMOS Output Test Configuration under Note 3.
- Updated Table 5.8 Performance Characteristics on page 32.
- Changed "Input-to-Output Delay" specification to "Zero-Delay Mode Input-to-Output Delay".
- Updated Table 5.12 Crystal Specifications on page 37.
- Updated Table 5.14 Absolute Maximum Ratings ^{1, 2, 3} on page 38.

Revision 1.1

August, 2017

- Refer to AN1006 for a list of changes from Rev B to Rev D.
- Updated block diagram on the front page.
- Minor changes to the following tables:
 - Table 5.3 Input Clock Specifications on page 26
 - Table 5.8 Performance Characteristics on page 32
 - Table 5.12 Crystal Specifications on page 37
 - Table 5.14 Absolute Maximum Ratings ^{1, 2, 3} on page 38

Revision 1.0

July, 2016

· Initial release.



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